NSN 5961-01-596-2889

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-596-2889
Overall Length:
Between 0.110 inches and 0.120 inches
Overall Height:
Between 0.035 inches and 0.043 inches
Overall Width:
Between 0.084 inches and 0.098 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
12.0 collector to base voltage, dc and 12.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, dc
Current Rating Per Characteristic:
80.0 milliamperes collector current, dc
Power Rating Per Characteristic:
350.0 milliwatts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0